# UNISONIC TECHNOLOGIES CO., LTD

# **UP1752**

## NPN SILICON TRANSISTOR

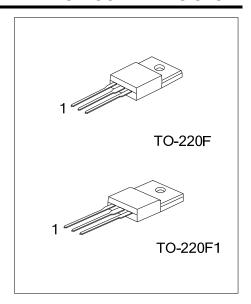
# HIGH CURRENT LOW V<sub>CE(SAT)</sub> TRANSISTOR

#### DESCRIPTION

The UTC UP1752 is specially designed to have high current and low V<sub>CE(SAT)</sub> to suit for power amplifier application and power switching application.

#### **FEATURES**

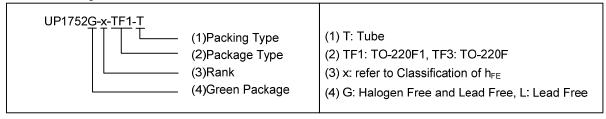
\*Low Collector-Emitter Saturation Voltage: V<sub>CE(SAT)</sub> = 300mV (Max.) @ 4.0A



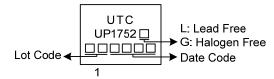
#### ORDERING INFORMATION

Ordering Number		Daakana	Pin Assignment			Daakina	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UP1752L-x-TF1-T	UP1752G-x-TF1-T	TO-220F1	В	С	Е	Tube	
UP1752L-x-TF3-T	UP1752G-x-TF3-T	TO-220F	В	С	Е	Tube	

Note: Pin Assignment: B: Base C: Collector E: Emitter



#### **MARKING**



<sup>\*</sup> BV<sub>CEO</sub> is 100V minimum

## ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Continuous Collector Current	lc	6	Α
Continuous Base Current	lΒ	0.5	Α
Collector Power Dissipation (T <sub>C</sub> =25°C)	Pc	30	W
Junction Temperature	TJ	+150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~ <b>+</b> 150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

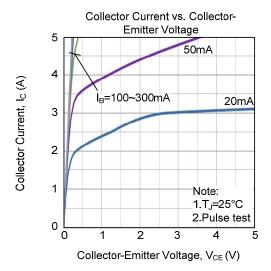
# ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C, unless otherwise specified)

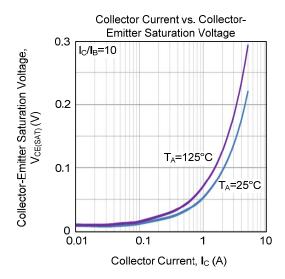
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =50mA, I <sub>B</sub> =0	100			V
Collector Cut-Off Current	Ісво	V <sub>CB</sub> =100V, I <sub>E</sub> =0			10	nA
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0			10	nA
DC Current Gain	h <sub>FE1</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =1A	70		240	
	h <sub>FE2</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =4A	20			
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>B</sub> =0.4A, I <sub>C</sub> =4A			300	mV
Base-Emitter Voltage	V <sub>BE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =1A			1100	mV
Transition Frequency	f⊤	V <sub>CE</sub> =5V, I <sub>C</sub> =1A		30		MHz
Collector Output Capacitance	Cob	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		40		pF

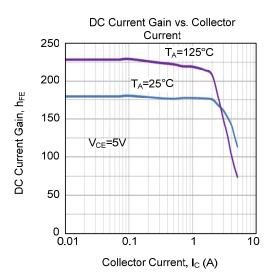
## ■ CLASSIFICATION OF h<sub>FE1</sub>

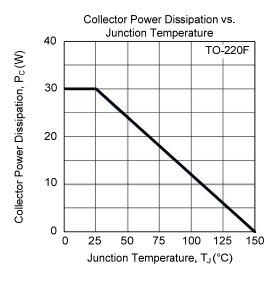
RANK	0	Υ
RANGE	70 ~ 140	120 ~ 240

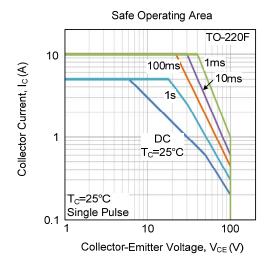
#### ■ TYPICAL CHARACTERISTICS











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